Preliminary TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

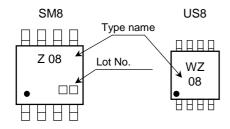
TC7WZ08FU,TC7WZ08FK

2 Input and Gate

Features

- High output drive: ± 24 mA (min) @V_{CC} = 3 V
- Super high speed operation: t_{pd} 2.4 ns (typ.) @VCC = 5 V,
- Operation voltage range: $V_{CC\ (opr)} = 1.65 \sim 5.5\ V$
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA) ±2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

Marking



TC7WZ08FU SSOP8-P-0.65 TC7WZ08FK SSOP8-P-0.50A

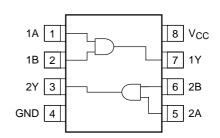
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	-0.5~6	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	-20	mA
DC output current	I _{OUT}	±50	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	P _D	300 (SM8) 200 (US8)	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10s)	T_L	260	°C

Pin Assignment (top view)



Truth Table

Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

Logic Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vaa	1.65~5.5	V	
Supply voltage	Vcc	1.5~5.5 (Note 1)	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note 2)	V	
		0~V _{CC} (Note 3)		
Operating temperature	T _{opr}	-40~85	°C	
		0~20 (V_{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V)	ns/V	
Input rise and fall time	d _t /d _V	$0 \sim 10 \; (V_{CC} = 3.3 \; V \pm 0.3 \; V)$		
		$0 \sim 5 \text{ (V}_{CC} = 5.5 \text{ V} \pm 0.5 \text{ V)}$		

Note 1: Data retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics		Cumbal	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Linit
		Symbol	rest	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High level	High lovel	igh level V _{IH}			1.65~1.95	0.75 × V _{CC}	_	_	0.75 × V _{CC}	_	
	VIH	_		2.3~5.5	0.7 × V _{CC}	_	_	0.7 × V _{CC}	_	V	
voltage	Low level	.,	_		1.65~1.95		_	0.25 × V _{CC}	_	0.25 × V _{CC}	V
	Low level	V _{IL}			2.3~5.5		_	0.3 × V _{CC}	_	0.3 × V _{CC}	
					1.65	1.55	1.65	_	1.55	_	
				I _{OH} = -100 μA	2.3	2.2	2.3	—	2.2	_	
				10Η – - 100 μΑ	3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
	High level	V _{OH}	$V_{IN} = V_{IH}$	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52	_	1.29	_	V
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	
				I _{OH} = -16 mA	3.0	2.4	2.8	_	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
Output				I _{OH} = -32 mA	4.5	3.8	4.2	_	3.8	_	
voltage		V _{OL}	V _{IN} = V _{IH} or V _{IL}	Ι _{ΟL} = 100 μΑ	1.65	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	-
					4.5	_	0	0.1	_	0.1	
	Low level			I _{OL} = 4 mA	1.65	_	0.08	0.24	_	0.24	
				I _{OL} = 8 mA	2.3	_	0.1	0.3	_	0.3	
				I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55	
				I _{OL} = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage	current	t I _{IN} V _{IN} = 5.5 V or GND		or GND	0~5.5		_	±1	_	±10	_
Power off leal	kage current	l _{OFF}	V _{IN} or V _{OL}	_{IT} = 5.5 V	0.0			1		10	μΑ
Quiescent supply current		Icc	V _{IN} = 5.5 V	or GND	1.65~5.5	_		1		10	μΑ

AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol Test Condition			Ta = 25°C Ta = -40~8				0~85°C	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	^t pLH ^t pHL	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	1.8 ± 0.15	2.0	5.7	10.5	2.0	11.0	- ns
			2.5 ± 0.2	1.0	3.5	5.8	1.0	6.2	
			3.3 ± 0.3	0.8	2.6	3.9	0.8	4.3	
			5.0 ± 0.5	0.5	1.9	3.1	0.5	3.3	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	3.3 ± 0.3	1.2	3.2	4.8	1.2	5.2	
			5.0 ± 0.5	0.8	2.5	3.7	0.8	4.0	
Input capacitance	C _{IN}	_	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	C _{PD} (Note)	(Note)	3.3	_	22	_	_	_	»E
		5.5		37	_	_	_	pF	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

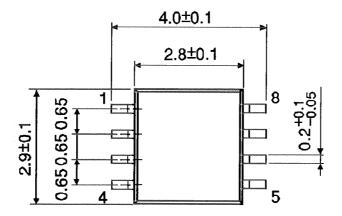
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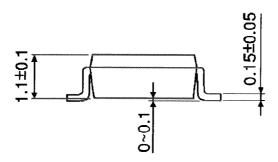
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

Package Dimensions

SSOP8-P-0.65 Unit: mm

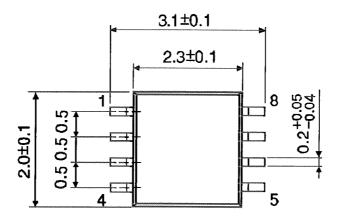


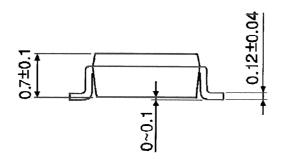


Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A Unit: mm





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Weight: 0.01 g (typ.)

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